

XN04313 (XN4313)

Silicon NPN epitaxial planar transistor (Tr1)
Silicon PNP epitaxial planar transistor (Tr2)

For switching/digital circuit

■ Features

- Two elements incorporated into one package
(Transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

■ Basic Part Number of Element

- UNR1213 (UN1213) + UNR1113 (UN1113)

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

	Parameter	Symbol	Rating	Unit
Tr1	Collector to base voltage	V_{CBO}	50	V
	Collector to emitter voltage	V_{CEO}	50	V
	Collector current	I_C	100	mA
Tr2	Collector to base voltage	V_{CBO}	-50	V
	Collector to emitter voltage	V_{CEO}	-50	V
	Collector current	I_C	-100	mA
Total	Total power dissipation	P_T	300	mW
	Junction temperature	T_j	150	°C
	Storage temperature	T_{stg}	-55 to +150	°C

■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

- Tr1

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector to base voltage	V_{CBO}	$I_C = 10 \mu\text{A}, I_E = 0$	50			V
Collector to emitter voltage	V_{CEO}	$I_C = 2 \text{ mA}, I_B = 0$	50			V
Collector cutoff current	I_{CBO}	$V_{CB} = 50 \text{ V}, I_E = 0$			0.1	μA
	I_{CEO}	$V_{CE} = 50 \text{ V}, I_B = 0$			0.5	
Emitter cutoff current	I_{EBO}	$V_{EB} = 6 \text{ V}, I_C = 0$			0.1	mA
DC current gain	h_{FE}	$V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}$	80			
Collector to emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C = 10 \text{ mA}, I_B = 0.3 \text{ mA}$			0.25	V
High-level output voltage	V_{OH}	$V_{CC} = 5 \text{ V}, V_B = 0.5 \text{ V}, R_L = 1 \text{ k}\Omega$	4.9			V
Low-level output voltage	V_{OL}	$V_{CC} = 5 \text{ V}, V_B = 3.5 \text{ V}, R_L = 1 \text{ k}\Omega$			0.2	V
Input resistance	R_I		-30%	47	+30%	$\text{k}\Omega$
Resistance ratio	R_I/R_2		0.8	1.0	1.2	
Gain bandwidth product	f_T	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$		150		MHz

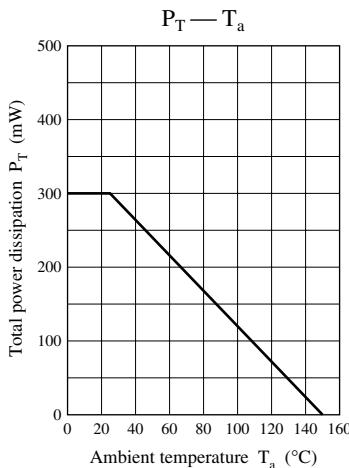
Note) The part number in the parenthesis shows conventional part number.

■ Electrical Characteristics (continued) $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

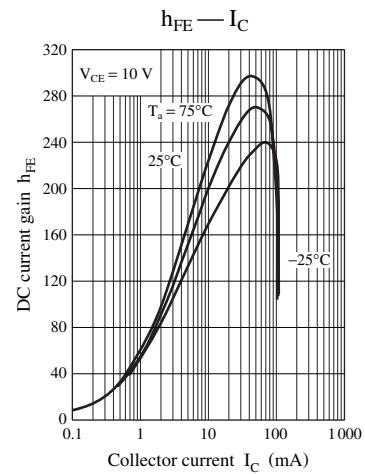
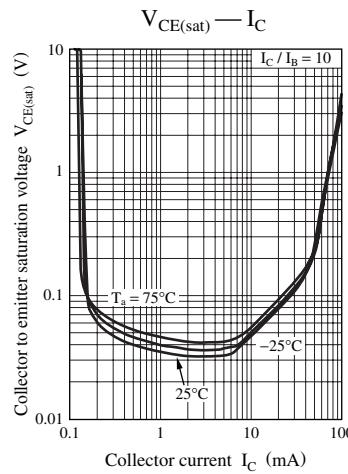
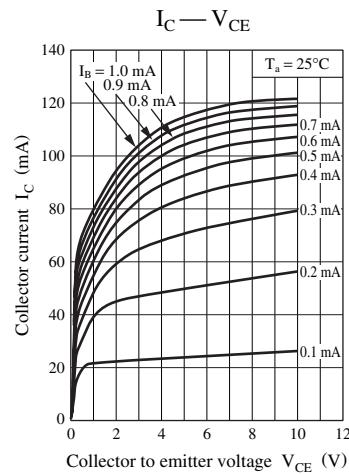
- Tr2

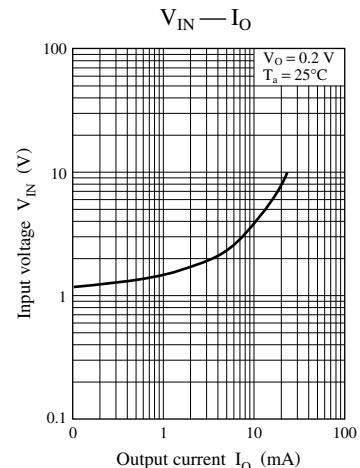
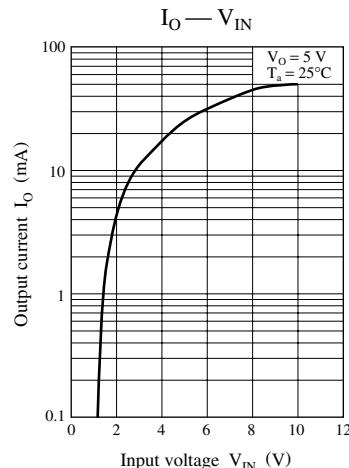
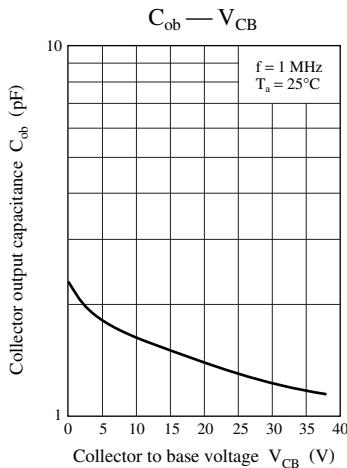
Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Collector to base voltage	V_{CBO}	$I_C = -10 \mu\text{A}, I_E = 0$	-50			V	
Collector to emitter voltage	V_{CEO}	$I_C = -2 \text{ mA}, I_B = 0$	-50			V	
Collector cutoff current	I_{CBO}	$V_{\text{CB}} = -50 \text{ V}, I_E = 0$			-0.1	μA	
	I_{CEO}	$V_{\text{CE}} = -50 \text{ V}, I_B = 0$			-0.5		
Emitter cutoff current	I_{EBO}	$V_{\text{EB}} = -6 \text{ V}, I_C = 0$			-0.1	mA	
DC current gain	h_{FE}	$V_{\text{CE}} = -10 \text{ V}, I_C = -5 \text{ mA}$	80				
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	$I_C = -10 \text{ mA}, I_B = -0.3 \text{ mA}$			-0.25	V	
High-level output voltage	V_{OH}	$V_{\text{CC}} = -5 \text{ V}, V_B = -0.5 \text{ V}, R_L = 1 \text{ k}\Omega$	-4.9			V	
Low-level output voltage	V_{OL}	$V_{\text{CC}} = -5 \text{ V}, V_B = -3.5 \text{ V}, R_L = 1 \text{ k}\Omega$			-0.2	V	
Input resistance	R_I			-30%	47	+30%	$\text{k}\Omega$
Resistance ratio	R_I/R_2			0.8	1.0	1.2	
Gain bandwidth product	f_T	$V_{\text{CB}} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80			MHz

Common characteristics chart

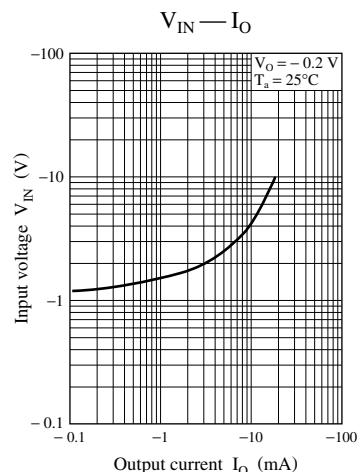
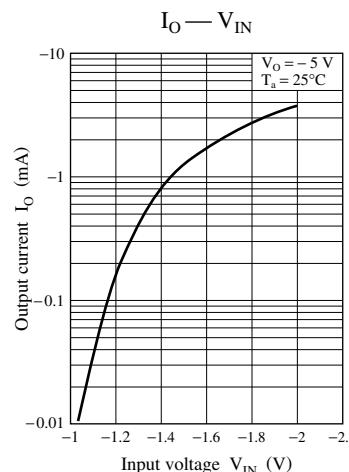
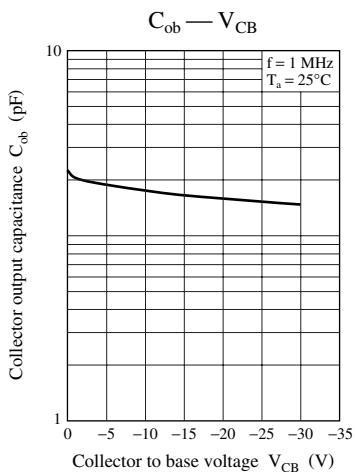
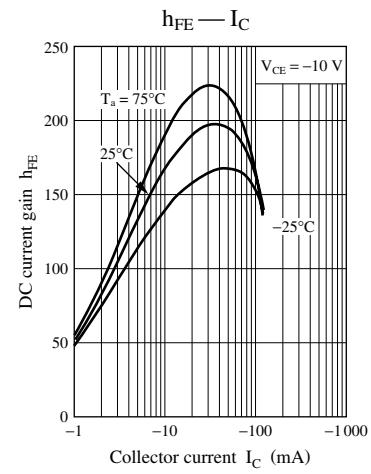
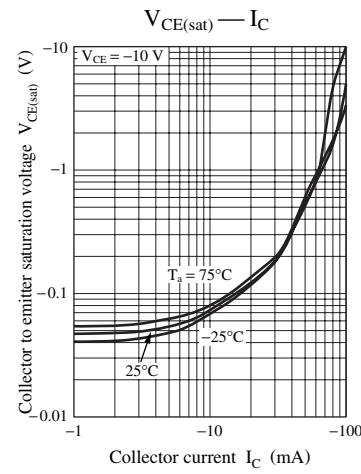
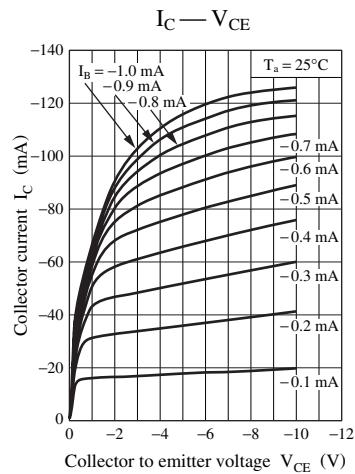


Characteristics chart of Tr1





Characteristics chart of Tr2



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